Notice of References Cited

	Application/Control No. 10/550,670	Reexamination	Applicant(s)/Patent Under Reexamination FUNAHASHI, RYOJI		
f	Examiner	Art Unit			
	Kallambella Vijayakumar	1751	Page 1 of 1		

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	Α	US-2001/0025494	10-2001	Okamura et al.	62/6
*	В	US-2001/0016554	08-2001	Takeuchi, Masahiko	502/303
*	С	US-5,352,299	10-1994	Yoshimoto et al.	136/201
*	D	US-6,129,862	10-2000	Munakata et al.	252/519.15
	Ε	US-			
	F	US-			
	G	US-			
	Н	US-			
	-	US-	•		
	J	US-			
	Κ	US-			
	L	US-			
	. М	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N	JP 06-315634	11-1994	JP ·	Nakatsuji et al	B01J 29/36
*	0	EP.714850	11-1995	JP	Saegusa et al	C01B 13/14
	Р	JP 2003-282964	10-2003	JP	Funahashi et al	H01L 35/22
	α					
	R					
	s					•
	Т					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Funahashi et al, "Thermoelectric properties of Ln-Ni-O (Ln-Lanthanoid) systems," 22nd International Conf. on Thermolectrics, 2003, PP 184-187.
	٧	Rao et al, "A comparative study of the magnetic and electrical properties of perovskite oxides and corresponding two- dimensional oxides of K2NiF4 Structure," J. Soild. St. Chem., 1988, 72, PP 14-23.
	w	
	x	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.